

# CSRI2×75-065P3B

### SIC SCHOTTKY DIODE TYPE 2×75A

• Temperature Independent Switching Behavior

### **Features**

- High surge current capable
- Zero reverse recovery current VDC
- High bandwidth
- Isolation type package

## **Benefits**

- Unipolar rectifier
- Zero switching loss
- Higher efficiency

### **Applications**

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment

• IF (Tc<135°C) 2×75 A

650 V

- Smaller heat sink
- Parallel devices without thermal runaway
- Power factor correction
- Diode snubber
- Automotive
- induction heating

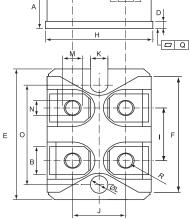
### **Maximum Ratings**

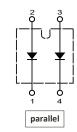
Operating Junction Temperature : - 55  $^{\circ}$ C to +175  $^{\circ}$ C storage Temperature : - 55  $^{\circ}$ C to +175  $^{\circ}$ C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×75-065P3B	650V	650V

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I <sub>F</sub>	T <sub>c</sub> =135 °C	75		
Surge non-repetitive forward current	I <sub>FSM</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	600		
sine halfwave (per diode)	-131	T <sub>C</sub> =150 °C, t <sub>p</sub> =8.3 ms	375	А	
Non-repetitive peak forward current	I <sub>F,max</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =10 $\mu$ s	2400		
(per diode)		T <sub>C</sub> =150 °C, $t_p$ =10 $\mu$ s	1500		
Repetitive peak reverse voltage	$V_{RRM}$	T <sub>j</sub> =25 °C	650	V	
Isolation voltage between All Terminals and Baseplate	V <sub>iso</sub>	50/60 Hz, t=1min I <sub>ISOL</sub> ≤ 1mA	2500	V	
Mounting torque		To heatsink	1.3	Nm	
		To terminal	1.1		







DIMENSIONS						
	INC	HES	М	М		
	MIN	MAX	MIN	MAX		
А	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
Е	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	1.008	25.30	25.60		
I	0.579	0.602	14.70	15.30		
J	0.492	0.516	12.50	13.10		
K	0.161	0.169	4.10	4.30		
L	0.161	0.169	4.10	4.30		
М	0.181	0.197	4.60	5.00		
Ν	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05	0.10		
R	M4*8					

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#### **Electrical Characteristics**, at $T_1$ =25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V <sub>DC</sub>		650	-	-	
	V <sub>F</sub>	I <sub>F</sub> =75A, T <sub>j</sub> =25 °C	-	1.5	1.7	V
Diode forward voltage		I <sub>F</sub> =75A, T <sub>j</sub> =175 °C	-	1.9	2.2	
	1-	V <sub>R</sub> =650V, T <sub>j</sub> =25 °C	-	50	80	
Reverse current	I <sub>R</sub>	V <sub>R</sub> =650V, T <sub>j</sub> =175 °C	-	80	300	μA

#### AC Characteristics (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	Q <sub>rr</sub>	V <sub>R</sub> =400V, T <sub>j</sub> =25 °C	-	126	-	nC
Total capacitance	С	V <sub>R</sub> =1V, f=1 MHz T <sub>j</sub> =25 °C	-	3176	-	pF
		V <sub>R</sub> =200V, f=1 MHz T <sub>j</sub> =25 °C	-	353	-	
		V <sub>R</sub> =400V, f=1 MHz T <sub>j</sub> =25 °C	-	270	-	

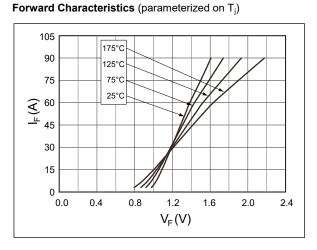
#### Thermal Characteristics (per diode)

Static Characteristics	Symphol	Values		
Static Characteristics	Symbol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta  JC}$	0.18	°C/W	



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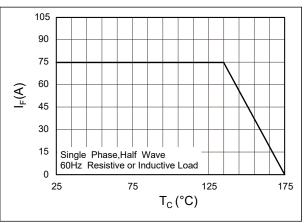
#### **Typical Performance**



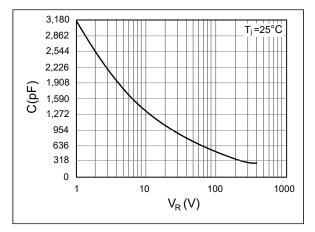
#### 1.0 175°C 125°C 75°0 0.1 I<sub>R</sub>(mA) 25°C 0.01 0 0 10 20 30 40 50 60 70 80 90 100 Volts (%)

#### Reverse Characteristics (parameterized on Tj)

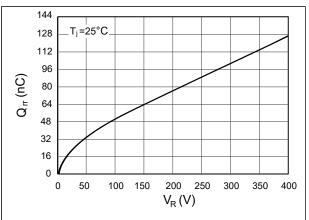




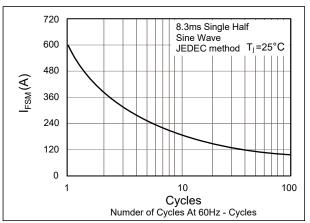
#### Capacitance



### **Recovery Charge**









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